VS-16CTQ060-M3, VS-16CTQ080-M3, VS-16CTQ100-M3

**Vishay Semiconductors** 

# High Performance Schottky Rectifier, 2 x 8 A



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PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 8 A			
V <sub>R</sub>	60 V, 80 V, 100 V			
V <sub>F</sub> at I <sub>F</sub>	0.58 V			
I <sub>RM</sub> max.	7 mA at 125 °C			
T <sub>J</sub> max.	175 °C			
E <sub>AS</sub>	7.5 mJ			
Package	TO-220AB 3L			
Circuit configuration	Common cathode			

### **FEATURES**

- 175 °C T<sub>J</sub> operation
- Low forward voltage drop
- High frequency operation



COMPLIANT

HALOGEN

FREE

- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

## DESCRIPTION

This center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I <sub>F(AV)</sub>	Rectangular waveform	16	А			
V <sub>RRM</sub>		60 to 100	V			
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	850	А			
V <sub>F</sub>	8 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (per leg)	0.58	V			
TJ	Range	-55 to +175	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-16CTQ060-M3	VS-16CTQ080-M3	VS-16CTQ100-M3	UNITS	
Maximum DC reverse voltage	V <sub>R</sub>	60	80	100	V	
Maximum working peak reverse voltage	V <sub>RWM</sub>	00	00	100	v	

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward per l	<i>с</i> .	$I_{F(AV)}$ 50 % duty cycle at T <sub>C</sub> = 148 °C, rectangular waveform		8	A	
current, see fig. 5 per devi				16		
Maximum peak one cycle non-repetitiv		5 μs sine or 3 μs rect. pulse Following any ra		850	А	
surge current per leg, see fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	rated V <sub>RRM</sub> applied	275	~	
Non-repetitive avalanche energy per le	g E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 0.50 A, L = 60 mH		7.50	mJ	
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to ze Frequency limited by T <sub>J</sub> maxing		0.50	А	

 Revision: 28-Feb-2023
 1
 Document Number: 96272

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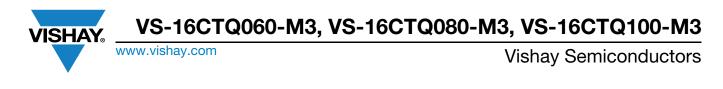
ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
		8 A	T <sub>.1</sub> = 25 °C	0.72	v	
Maximum forward voltage drop per leg	V <sub>FM</sub> <sup>(1)</sup>	16 A	1j=23 0	0.88		
See fig. 1	VFM ()	8 A	T <sub>.1</sub> = 125 °C	0.58		
		16 A	1j = 125 C	0.69		
Maximum reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	) (	0.55	mA	
See fig. 2	IRM (")	T <sub>J</sub> = 125 °C	V <sub>R</sub> = rated V <sub>R</sub>	7.0		
Threshold voltage	V <sub>F(TO)</sub>			0.415	V	
Forward slope resistance	r <sub>t</sub>	$T_J = T_J maximum$		11.07	mΩ	
Maximum junction capacitance per leg	CT	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		500	pF	
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 mm from package body		8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs	

### Note

SHAY

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SP	PECIFICA	TIONS			
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55 to 175	°C	
Maximum thermal resistance, junction to case per leg	R <sub>thJC</sub>	DC operation	3.25	°C/W	
Maximum thermal resistance junction to case per package	R <sub>thJC</sub>		1.63	0/10	
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50		
Approximate weight			2	g	
Approximate weight			0.07	oz.	
Mounting to your			6 (5)	kgf∙cm	
Mounting torque maximum			12 (10)	(lb̃f · in)	
			16CT	Q060	
Marking device		Case style TO-220AB 3L	16CT	Q080	
			16CTQ100		



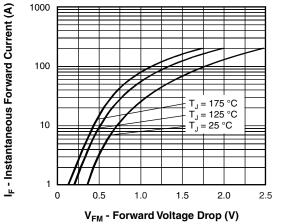




Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

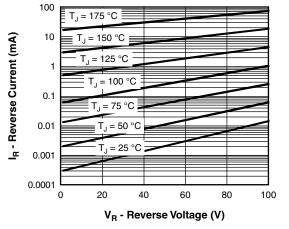


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

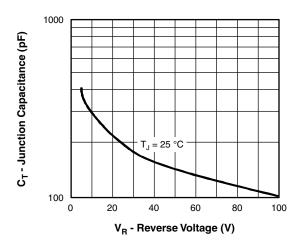


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

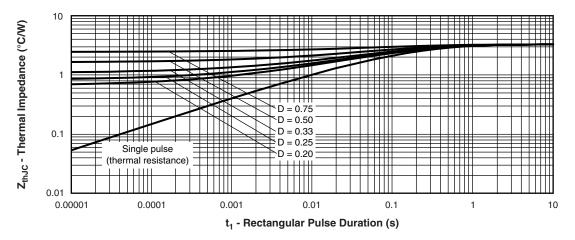
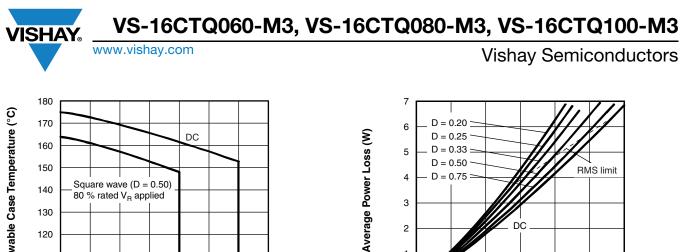
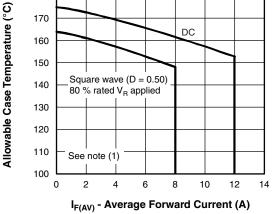
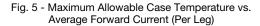


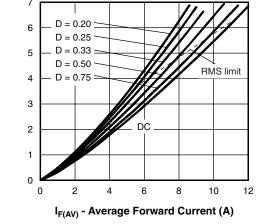
Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

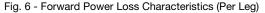
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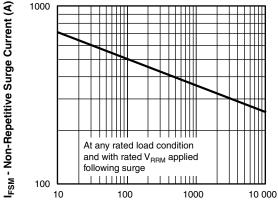












t<sub>n</sub> - Square Wave Pulse Duration (µs)

Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

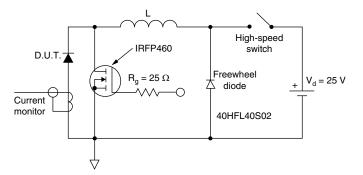


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ; (1) Pd = forward power loss =  $I_{F(AV)} \times V_{FM}$  at ( $I_{F(AV)}/D$ ) (see fig. 6);

 $Pd_{REV}$  = inverse power loss =  $V_{B1} \times I_B (1 - D)$ ;  $I_B$  at  $V_{B1}$  = 80 % rated  $V_B$  applied

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## **ORDERING INFORMATION TABLE**

VISHAY

Device code	VS-	16	с	т	Q	100	-M3
	1	2	3	4	5	6	7
	1 2 3	- Cur - Circ	hay Sem rrent rati cuit confi	ng (16 = iguratior	: 16 A) า	oduct	
	4		kage TO-220	)		_	
	5		ottky "Q				060 = 60 V 080 = 80 V
	6		tage rati /ironmer	0			100 = 100 V
				0		complia	ant and torn

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION			
VS-16CTQ060-M3	50	Antistatic plastic tubes			
VS-16CTQ080-M3	50	Antistatic plastic tubes			
VS-16CTQ100-M3	50	Antistatic plastic tubes			

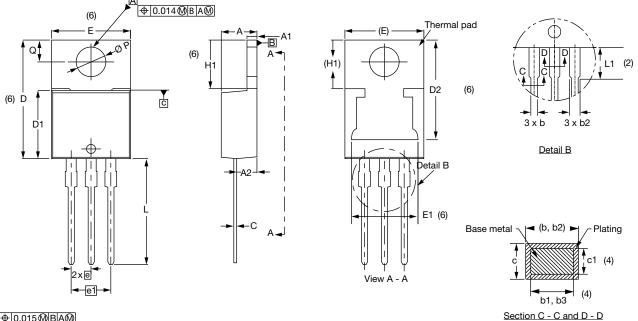
LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?96154				
Part marking information	www.vishay.com/doc?95028			
SPICE model	www.vishay.com/doc?95279			



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## **TO-220AB 3L**

## **DIMENSIONS** in millimeters and inches



⊕0.015@BA@



SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

MILLIMETERS	INCHES

Conforms to JEDEC<sup>®</sup> outline TO-220AB

SYMBOL			INCITEO		NOTES
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	13.30	0.460	0.524	6, 7
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

Notes

 $^{(1)}\,$  Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Lead dimension and finish uncontrolled in L1

(3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

<sup>(4)</sup> Dimension b1, b3, and c1 apply to base metal only

(5) Controlling dimensions: inches

<sup>(6)</sup> Thermal pad contour optional within dimensions E, H1, D2, and E1

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> TO-220, except D2

Revision: 22-Feb-2024

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Revision: 01-Jan-2025

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